1N4001, 1N4002, 1N4003, 1N4004, 1N4005, 1N4006, 1N4007

1N4004 and 1N4007 are Preferred Devices

Axial Lead Standard Recovery Rectifiers

This data sheet provides information on subminiature size, axial lead mounted rectifiers for general-purpose low-power applications.

Features

- Shipped in plastic bags, 1000 per bag
- Available Tape and Reeled, 5000 per reel, by adding a "RL" suffix to the part number
- Available in Fan-Fold Packaging, 3000 per box, by adding a "FF" suffix to the part number
- Pb-Free Packages are Available

Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 0.4 gram (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds, 1/16 in. from case
- Polarity: Cathode Indicated by Polarity Band



ON Semiconductor®

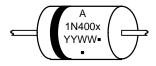
http://onsemi.com

LEAD MOUNTED RECTIFIERS 50-1000 VOLTS DIFFUSED JUNCTION



CASE 59-10 AXIAL LEAD PLASTIC

MARKING DIAGRAM



A = Assembly Location

1N400x = Device Number

x = 1, 2, 3, 4, 5, 6 or 7 YY = Year

WW = Work Week

= Pb-Free Package

ORDERING INFORMATION

(Note: Microdot may be in either location)

See detailed ordering and shipping information on page 4 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

^{*}For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1N4001, 1N4002, 1N4003, 1N4004, 1N4005, 1N4006, 1N4007

MAXIMUM RATINGS

Rating	Symbol	1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007	Unit
†Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	200	400	600	800	1000	V
†Non-Repetitive Peak Reverse Voltage (halfwave, single phase, 60 Hz)	V _{RSM}	60	120	240	480	720	1000	1200	V
†RMS Reverse Voltage	V _{R(RMS)}	35	70	140	280	420	560	700	V
†Average Rectified Forward Current (single phase, resistive load, 60 Hz, T _A = 75°C)	I _O	1.0							А
†Non-Repetitive Peak Surge Current (surge applied at rated load conditions)	I _{FSM}	30 (for 1 cycle)							Α
Operating and Storage Junction Temperature Range	T _J T _{stg}	-65 to +175							°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS†

Rating		Тур	Max	Unit
Maximum Instantaneous Forward Voltage Drop, (i _F = 1.0 Amp, T _J = 25°C)		0.93	1.1	V
Maximum Full-Cycle Average Forward Voltage Drop, (I _O = 1.0 Amp, T _L = 75°C, 1 inch leads)	V _{F(AV)}	-	0.8	V
Maximum Reverse Current (rated DC voltage) $ (T_J = 25^{\circ}C) $ $ (T_J = 100^{\circ}C) $	I _R	0.05 1.0	10 50	μΑ
Maximum Full-Cycle Average Reverse Current, (I _O = 1.0 Amp, T _L = 75°C, 1 inch leads)	I _{R(AV)}	-	30	μΑ

[†]Indicates JEDEC Registered Data

1N4001, 1N4002, 1N4003, 1N4004, 1N4005, 1N4006, 1N4007

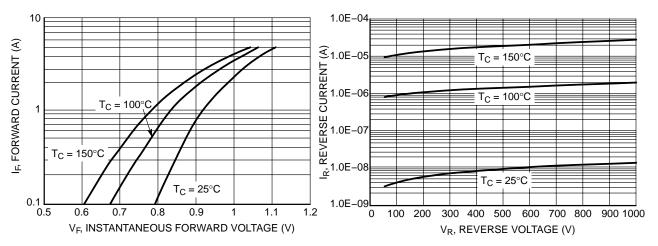


Figure 1. Typical Forward Voltage

Figure 2. Typical Reverse Current

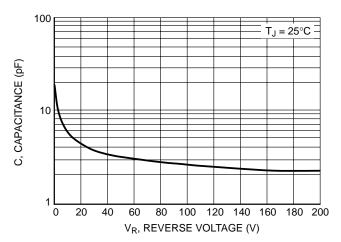


Figure 3. Typical Capacitance